# FPF2280 Over-Voltage Protection Load Switch

#### **Features**

- Surge Protection
  - IEC 61000-4-5: > 100 V
- Over-Voltage Protection (OVP)
- Over-Temperature Protection (OTP)
- ESD Protection
  - Human Body Model (HBM): > 3.5 kV
  - Charged Device Model (CDM): > 2 kV
  - IEC 61000-4-2 Air Discharge: > 15 kV
  - IEC 61000-4-2 Contact Discharge: > 8 kV

#### **Applications**

- Mobile Handsets and Tablets
- Portable Media Players
- MP3 Players

#### Description

The FPF2280 features a low- $R_{ON}$  internal FET and an operating range of 2.5  $V_{DC}$  to 5.5  $V_{DC}$  (absolute maximum of 29  $V_{DC}$ ). An internal clamp is capable of shunting surge voltages >100 V, protecting downstream components and enhancing system robustness. The FPF2280 features over-voltage protection that powers down the internal FET if the input voltage exceeds the OVP threshold. The OVP threshold is adjustable with optional external resistors. Over-temperature protection also powers down the device at 130°C (typical). Exceptionally low off-state current (<1  $\mu$ A maximum) facilitates compliance with standby power requirements.

The FPF2280 is available in a fully "green" compliant 1.3 mm × 1.8 mm Wafer-Level Chip-Scale Package (WLCSP) with backside laminate.

#### Related Resources

http://www.onsemi.com/

## **Ordering Information**

Part Number	Part Number Operating Temperature Range		Package	Packing Method	
FPF2280BUCX-F130	-40°C – 105°C	HC	12-Ball, 0.4 mm Pitch WLCSP	Tape & Reel	

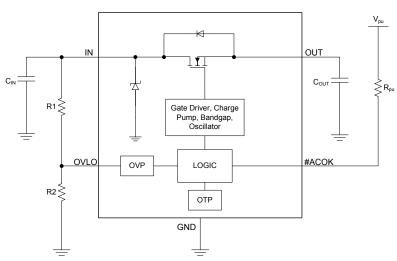
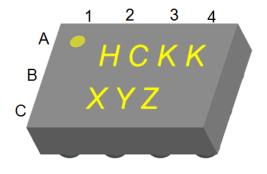


Figure 1. Functional Block Diagram

# **Pin Configuration**



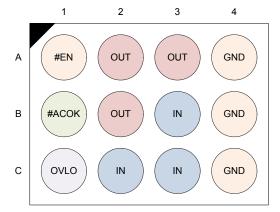
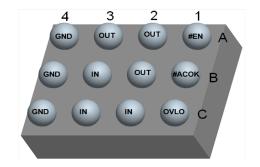


Figure 2. Pin Configuration (Top View)



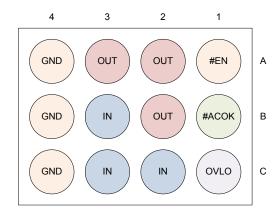


Figure 3. Pin Configuration (Bottom View)

#### **Pin Definitions**

Name	Bump	Туре	Description				
IN	B3, C2, C3	Input/Supply	Switch Input and Device Supply				
OUT	A2, A3, B2	Output	Switch Output to Load				
#ACOK	B1	Output	Power Good		$V_{IN} < V_{IN\_min}$ or $V_{IN} \ge V_{OVLO}$		
#ACOK BI		(Open Drain)	1 ower good		Voltage Stable		
#EN	A1	Input	Device Enable ( Active LOW)				
OVLO	C1	Input	Over-Voltage Lockout Adjustment Pin				
GND	A4, B4, C4	Supply	Device Ground				

# Over-Voltage Lockout (OVLO) Calculation

OVLO can be set externally and override default OVP. By connecting an external resistor-driver to the OVLO pin. Equation (1) can produce the desired trip voltage and resistor values.

$$V_{IN\_OLVO} = V_{OVLO\_TH} \times [1 + R1/R2] \tag{1}$$

Recommended minimum R1 = 1  $M\Omega$ .

#### On-The-Go (OTG) Functionality

During OTG operation, the FPF2280 is initially disabled and the power FET's bulk diode is forward biased. The bulk diode represents  $\sim 0.7$  V drop across the device, which remains until the V\_IN voltage increases past 2.5 V, when the device is fully enabled. While the device is disabled and the body diode is forward biased, the max DC current through the diode is 1.8 A. This current is limited by the thermal performance of the device

(0.7 Vx 1.8 A = 1.36 W). This current should be transient; the #EN pin must be pulled LOW to ensure the device fully enables. The transient should not exceed the RC time constant of the C\_IN and C\_OUT capacitors. At the system level, over-voltage and current protection should be provided outside the FPF2280.

#### **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter			Max.	Unit	
V <sub>IN</sub>	V_IN to GND & V_IN to V_OUT = GND or Float		-0.3	29.0	V	
V <sub>OUT</sub>	V_OUT to GND		-0.3	V <sub>IN</sub> + 0.3	V	
V <sub>OVLO</sub>	OVLO to GND		-0.3	24.0	V	
V#EN_ACOK	Maximum DC Voltage Allowed on #EN or ACOK Pin			6	V	
I <sub>IN</sub>	Switch I/O Current (Continuous)			4.5	Α	
t <sub>PD</sub>	Total Power Dissipation at T <sub>A</sub> = 25°C			1.48	W	
$T_{STG}$	Storage Temperature Range			+150	ç	
$T_J$	Maximum Junction Temperature			+150	°C	
$T_L$	Lead Temperature (Soldering, 10 Seconds)			+260	°C	
$\Theta_{JA}$	Thermal Resistance, Junction-to-Ambient <sup>(1)</sup> (1-in. <sup>2</sup> Pad of 2-oz. Copper)			84.1	°C/W	
	IEC 61000-4-2 System ESD	Air Gap	15.0			
FCD		Contact	8.0		127	
ESD	Human Body Model, ANSI/ESDA/JEDEC JS-001-2012	All Pins	3.5		kV	
	Charged Device Model, JESD22-C101 All Pins		2.0		<u> </u>	
Surge	IEC 61000-4-5, Surge Protection V <sub>IN</sub>		100		V	

#### Note:

1. Measured using 2S2P JEDEC std. PCB.

### **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. ON Semiconductor does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
$V_{IN}$	Supply Voltage	2.5	20.0	V
T <sub>A</sub>	Operating Temperature		+105	°C

#### **Electrical Characteristics**

 $T_A$  = -40°C to 105°C unless otherwise indicated. Typical values are  $V_{IN}$  = 5.0 V,  $I_{IN}$  ≤ 3 A,  $C_{IN}$  = 0.1  $\mu F$  and  $T_A$  = 25°C.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
V <sub>IN_CLAMP</sub>	Input Clamping Voltage	I <sub>IN</sub> = 10 mA		35		V
IQ	Input Quiescent Current	V <sub>IN</sub> = 5 V, #EN = 0 V		58	100	μΑ
I <sub>IN_Q</sub>	OVLO Supply Current	V <sub>OVLO</sub> = 3 V, V <sub>IN</sub> = 5 V, V <sub>OUT</sub> = 0 V		63	100	μΑ
	Internal Over Veltage Trip Level	V <sub>IN</sub> Rising, OVLO = GND	6.6	6.8	7.0	V
V <sub>IN_OVLO</sub>	Internal Over-Voltage Trip Level	V <sub>IN</sub> Falling	6.2			V
V <sub>OVLO_TH</sub>	OVLO Set Threshold	V <sub>IN</sub> = 2.5 V to V <sub>OVLO</sub>	1.12	1.20	1.24	V
V <sub>OVLO_RNG</sub>	Adjustable OVLO Threshold Range	V <sub>IN</sub> = 2.5 V to V <sub>OVLO</sub>	4		20	V
V <sub>OVLO_SELECT</sub>	External OVLO Select Threshold			0.30	0.28	V
R <sub>ON</sub>	Resistance from V <sub>IN</sub> to V <sub>OUT</sub>	V <sub>IN</sub> = 5 V, I <sub>OUT</sub> = 1 A. T <sub>A</sub> = 25°C		30	39	mΩ
C <sub>OUT</sub>	OUT Load Capacitance <sup>(2)</sup>	V <sub>IN</sub> = 5 V			1000	μF
I <sub>OLVO</sub>	OVLO Input Leakage Current	V <sub>OVLO</sub> = V <sub>OVLO_TH</sub>	-100		100	nA
$T_{SDN}$	Thermal Shutdown <sup>(2)</sup>			130		°C
T <sub>SDN_HYS</sub>	Thermal Shutdown Hysteresis <sup>(2)</sup>			20		°C
Digital Signa	als					•
V <sub>OL</sub>	#ACOK Output Low Voltage	V <sub>I/O</sub> = 3.3 V, I <sub>SINK</sub> = 1 mA			0.4	V
VIH_#EN	Enable HIGH Voltage	V <sub>IN</sub> = 2.5 V to V <sub>OVLO</sub>	1.2			V
VIL_#EN	Enable LOW Voltage	V <sub>IN</sub> = 2.5 V to V <sub>OVLO</sub>			0.5	V
I <sub>ACOK_LEAK</sub>	#ACOK Leakage Current	V <sub>I/O</sub> = 3.3 V, #ACOK Deasserted, #EN = 0 V	-0.5		0.5	μA
#EN_Leak	#EN Leakage Current	V <sub>IN</sub> = 5.0 V, V <sub>OUT</sub> = Float	-1.0		1.0	μA
Timing Char	acteristics				•	
t <sub>DEB</sub>	Debounce Time	Time from 2.5 V < V <sub>IN</sub> < V <sub>IN_OVLO</sub> to V <sub>OUT</sub> = 0.1 × V <sub>IN</sub>		15		ms
t <sub>START</sub>	Soft-Start Time	Time from $V_{IN}$ = $V_{IN\_min}$ to 0.2 × #ACOK, $V_{IO}$ = 1.8 V with 10 k $\Omega$ Pull-up Resistor		30		ms
ton	Switch Turn-On Time	$V_{IN}$ = 5 V, $R_{L}$ = 100 $\Omega$ , $V_{OUT}$ from 0.1 × $V_{IN}$ to 0.9 × $V_{IN}$ , $C_{LOAD}$ = 100 $\mu F$		2		ms
t <sub>OFF</sub>	Switch Turn-Off Time <sup>(2)</sup>	$R_L$ = 100 $\Omega$ , $C_L$ = 0 $\mu$ F, $V_{IN}$ > $V_{OVLO}$ to $V_{OUT}$ = 0.8 × $V_{IN}$		125		ns

#### Note:

2. Guaranteed by characterization and design.

# **Timing Diagrams**

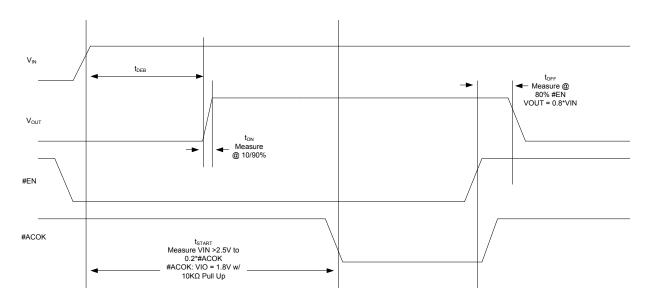


Figure 4. Timing for Power Up and Normal Operation

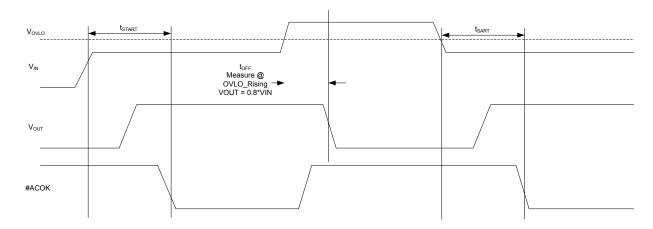


Figure 5. Timing for OVLO Trip

# **Product-Specific Package Dimensions**

D	E	X	Y	
1288 μm ±30 μm	1828 μm ±30 μm	314 μm ±18 μm	244 μm ±18 μm	

## **Physical Dimensions**

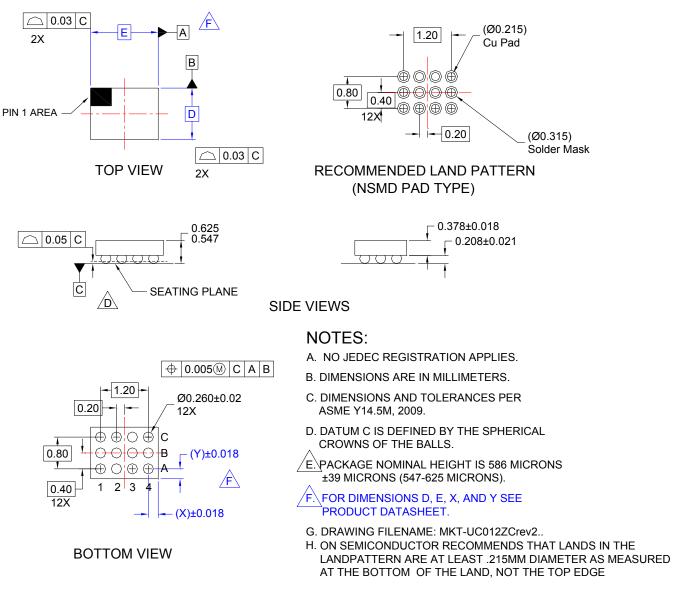


Figure 6. 12-Ball, 3×4 Array, 0.4 mm Pitch, Wafer-Level Chip-Scale Package (WLCSP)

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications using ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries,

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800-282-9855 Toll Free USA/Canada.

**Europe, Middle East and Africa Technical Support**: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative